



Features

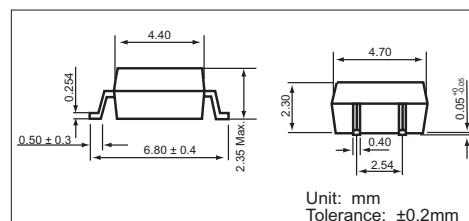
1. Normally open, single pole single throw.
2. Control 200VAC or DC voltage.
3. Switch 180mA loads.
4. LED control current, 5mA.
5. Low ON-resistance.
6. dv/dt, >500V/mS.
7. Isolation test voltage, 1500VRMS.
8. Package Type: SOP(shown)

Part Numbering System & Part Marking System: Page 3 & 4.

Absolute Maximum Ratings

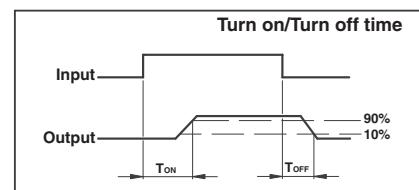
(Ta = 25°C)

Emitter (Input)	Detector(Output)
Reverse Voltage.....	5.0V
Continuous Forward Current	50mA
Peak Forward Current	1A
Power Dissipation.....	75mW
Derate Linearly from 25°C	1.3mW/°C
General Characteristics	
Isolation Test Voltage	1500VRMS
Isolation Resistance, VIO = 500V, TA = 25°C.....	>10 ¹⁰ Ω
Total Power Dissipation	500mW
Derate Linearly from 25°C	2.5mW/°C
Output Breakdown Voltage	±200V
Continuous Load Current	±180mA
Power Dissipation.....	.450mW
Storage Temperature Range ...	-40°C to +150°C
Operating Temperature Range	-40°C to +85°C
Junction Temperature	100°C
Soldering Temperature, 2mm from case, 10 sec.	260°C



WPPM-2024S

Unit: mm
Tolerance: ±0.2mm



Electro-optical Characteristics

(Ta = 25°C)

Parameter	Symbol	Conditions	Min.	Typ.	Max.	Unit
<i>Emitter (Input)</i>						
Forward Voltage	V _F	I _F = 10mA	-	1.2	1.5	V
Operation Input Current	I _{FON}	V _L = ±20V, I _L = 100mA, t = mS	-	1.5	5	mA
Recovery Input Current	I _{FOFF}	V _L = ±20V, I _L = <5uA	0.2	-	-	mA
<i>Detector(output)</i>						
Output Breakdown Voltage	V _B	I _B = 50uA	200	-	-	V
Output Off-State Leakage	I _{TOFF}	V _T = 100V, I _F = 0mA	-	0.2	1	uA
I/O Capacitance	C _{I/O}	I _F = 0, f = 1MHz	-	6	-	pF
ON Resistance	R _{ON}	I _L = 100mA, I _F = 10mA	-	6	15	Ω
Turn-On Time	T _{ON}	I _F = 10mA, V _L = ±20V	-	0.4	1.0	mS
Turn-Off Time	T _{OFF}	t = 10ms, I _L = ±100mA	-	0.3	1.0	mS

MOS Relay Schematic and Wiring Diagrams

Type	Schematic	Output Configuration	Load	Connection	Wiring Diagrams
2024S		1a	AC/DC	A	



ISOMOS™

WPPM-2024S Series

High Voltage, Photo MOS Relay

USR/CNR Listed (File# E223388)

Data Curves

Fig. 1 Load Current vs. Ambient Temperature
Allowable ambient temperature:
-40°C to +85°C

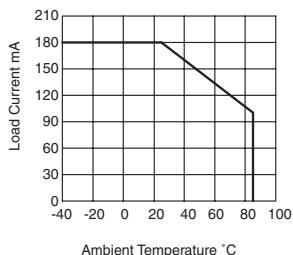


Fig. 2 On Resistance vs. Ambient Temperature Across Terminals 3 and 4 pin
LED current: 5mA
Continuous load current: 180mA (DC)

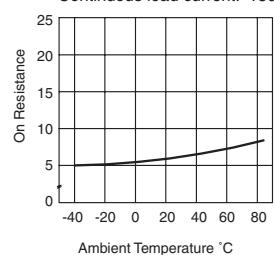


Fig.3 Turn on time vs. Ambient Temperature
Load voltage: 200V(DC)
LED current: 5mA
Continuous load current: 180mA(DC)

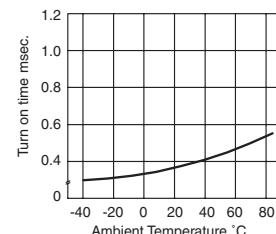


Fig. 4 Turn off time vs. Ambient Temperature
LED current: 5mA
Load voltage: 200V(DC)
Continuous load current: 180mA(DC)

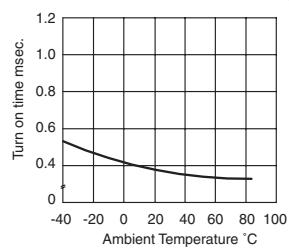


Fig. 5 LED operate vs. Ambient Temperature
Load voltage: 200V(DC)
Continuous load current: 180mA(DC)

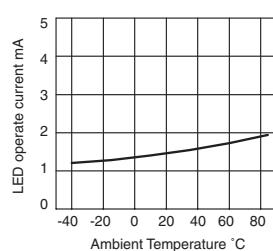


Fig. 6 LED turn off current vs. Ambient Temperature
Load voltage: 200V(DC)
Continuous load current: 180mA(DC)

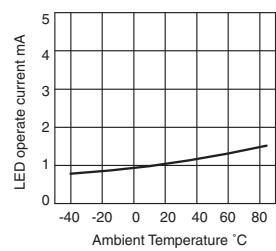


Fig. 7 LED Dropout Voltage vs.
Ambient Temperature
LED current: 5 to 50mA

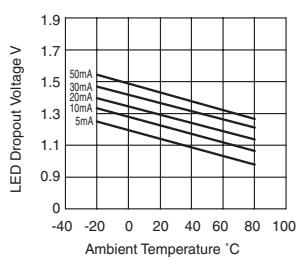


Fig. 8 Voltage vs. Current Characteristics
of output at MOSFET portion
Measured portion:
Across terminals 3 & 4 pin
Ambient Temperature: 25°C

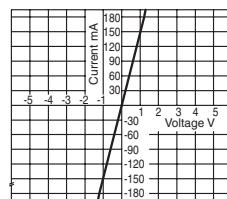


Fig. 9 LED forward current vs. turn on time
Across terminals 3 and 4 pin
Load voltage: 200V(DC)
Continuous load current: 180mA(DC)
Ambient Temperature: 25°C

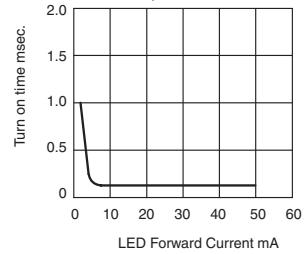


Fig. 10 Off State Leakage Current
Across terminals 3 and 4 pin
Ambient Temperature: 25°C

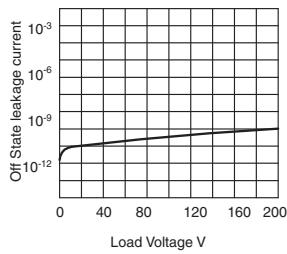


Fig. 11 LED forward current vs. turn off time
Across terminals 3 and 4 pin
Load voltage: 200V(DC)
Continuous load current: 180mA(DC)
Ambient Temperature: 25°C

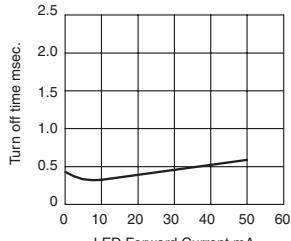


Fig. 12 Applied voltage vs. Output Capacitance
Across terminals 3 and 4 pin
Frequency: 1MHz
Ambient Temperature: 25°C

